Mechanical characterization of SLID bonded Au-Sn and Cu-Sn interconnections for MEMS packaging

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Outline

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- Shear and tensile test setups
- Mixed Flow Gas (MFG) test
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 - *Results from mechanical tests of As bonded samples*
 - o Mechanical strength after MFG test

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Objectives and methods

 The objective of this communication is to investigate mechanical properties of Au-Sn and Cu-Sn SLID bonded seal rings for hermetic MEMS packaging with shear and tensile tests



 Another objective is to study corrosion resistance of these bonds with Mixed Flow Gas test

Principles of SLID bonding





Bonding parameters and test structures



Group	Temperature (K)	Bonding pressure (MPa)	Bonding time (min)
AuSn1	593	2.4	60
AuSn2	593	2.4	60
AuSn3	623	14.4	60
CuSn1	623	14.4	60



Shear test setup











Mixed Flow Gas (MFG) test

- Corrosion properties of SLID bonds are rarely tested
- Pressure Cooking Test is used in some situations
 - However, only pressure, temperature and humidity as a corrosive agents (lacks corrosive gases)
 - -> Mixed Flow Gas test
- Weiss WKI1 600/40 Environmental test chamber system
 - Test based on Telcordia GR-63-CORE standard "Outdoor" conditions
 - Corrosion monitoring: ASTM-B810 with copper plate mass growth method
 - Vaisala HMT 333 for humidity/temperature measuring

Humidity (%RH)	Temperature (°C)	H ₂ S (µg/m³)	NO ₃ (µg/m³)	Cl ₂ (µg/m³)	SO ₂ (µg/m³)
70	30	262	188	19	136



Microstructural analysis results

AuSn1







Microstructural analysis results





Results from mechanical tests of As Bonded samples AuSn2 Shear

Aalto EILB

SEI

15.0kV

X80

	Shear Strength (MPa)	StDev	Tensile Strength (MPa)	StDev
AuSn 1	66	8	24	5
AuSn 2	112	26	41	9
AuSn 3	170	35	88	23
CuSn 1	275	42	91	27

AuSn1 Shear

 Aalto EILB
 SEI
 15.0kV
 X75
 100µm
 WD 15.3mm

Au₅Sn Mode III Si Aalto EILB SEI 10.0kV WD 15.3m X80 100*µ*m K AuSn2 Tensile Shortcut Mode II Mode Ti(W) Si Marrie View SAME S Silicon Au₅Sn mas. " of 2

100µm WD 14.9mm



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Au₅Sn Cu/Cu₃Sn/

Cu

Results from mechanical tests of As Bonded samples



AuSn3 Shear



AuSn3 Tensile



CuSn1 Shear



CuSn1 Tensile



Mechanical strength after MFG test







Mechanical strength after MFG test





Conclusions

- Cu-Sn bonding possess high shear and tensile strength
- Au-Sn bonding with Ni barrier demonstrates high shear and tensile strength
- Non-optimal interfaces, i.e. when (Au₅Sn+AuSn)_{eut} is directly in contact with the TiW adhesion layer, are susceptible to corrosive environments
- The results highlight the need to carefully design the thicknesses of metallization layers with respect to the bonding parameters in order to avoid the formation of mechanically weak interfaces and voids
- Design rules: Control Au/Sn ratio, thin Ni barrier between AuSn and TiW, Amount of Sn vs. bonding parameters in Cu bonding



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Questions please?

